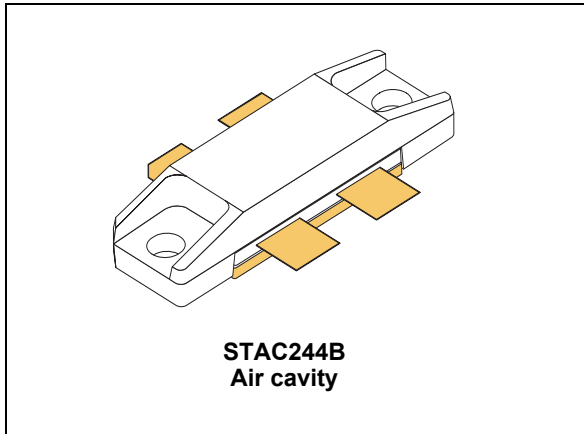


## HF/VHF/UHF RF power N-channel MOSFET

Datasheet - production data



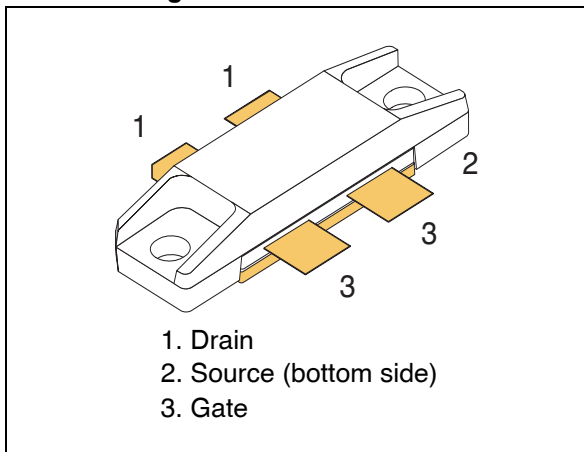
### Features

- Excellent thermal stability
- Common source push-pull configuration
- $P_{OUT} = 580\text{ W typ. with } 24.6\text{ dB gain @ } 123\text{ MHz}$
- In compliance with the 2002/95/EC European directive

### Description

The STAC3932B is an N-channel MOS field-effect RF power transistor. It is intended for use in 100 V DC large signal applications up to 250 MHz.

**Figure 1. Pin connection**



**Table 1. Device summary**

Order code	Marking	Base qty.	Package	Packaging
STAC3932B	STAC3932 <sup>(1)</sup>	20	STAC244B	Plastic tray

1. For more details please refer to [Chapter 8: Marking, packing and shipping specifications](#).

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# 1 Electrical data

## 1.1 Maximum ratings

Table 2. Absolute maximum ratings ( $T_{CASE} = 25\text{ °C}$ )

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}^{(1)}$	Drain source voltage	250	V
$V_{DGR}$	Drain-gate voltage ( $R_{GS} = 1\text{ M}\Omega$ )	250	V
$V_{GS}$	Gate-source voltage	$\pm 20$	V
$I_D$	Drain current	20	A
$P_{DISS}$	Power dissipation	625	W
$T_J$	Max. operating junction temperature	200	$^{\circ}\text{C}$
$T_{STG}$	Storage temperature	-65 to +150	$^{\circ}\text{C}$

1.  $T_J = 150\text{ °C}$

## 1.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thJC}$	Junction - case thermal resistance	0.28	$^{\circ}\text{C/W}$

## 2 Electrical characteristics

( $T_{CASE} = 25\text{ °C}$ )

### 2.1 Static

Table 4. Static (per side)

Symbol	Test conditions			Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	$V_{GS} = 0\text{ V}$	$I_{DS} = 100\text{ mA}$		250			V
$I_{DSS}$	$V_{GS} = 0\text{ V}$	$V_{DS} = 100\text{ V}$				1	mA
$I_{GSS}$	$V_{GS} = 20\text{ V}$	$V_{DS} = 0\text{ V}$				250	nA
$V_{TH}$	$I_D = 250\text{ mA}$			2.0		4.0	
$V_{DS(ON)}$	$V_{GS} = 10\text{ V}$	$I_D = 5\text{ A}$			2.5	3.5	V
$G_{FS}$	$V_{DS} = 10\text{ V}$	$I_D = 2.5\text{ A}$		3.0		5.0	S
$C_{ISS}$	$V_{GS} = 0\text{ V}$ $V_{DS} = 100\text{ V}$ $f = 1\text{ MHz}$				492		pF
$C_{OSS}$					134		pF
$CRSS$					5.2		pF

### 2.2 Dynamic

Table 5. Dynamic CW

Symbol	Test conditions	Min.	Typ.	Max.	Unit
$P_{OUT}$	$V_{DD} = 100\text{ V}$ , $I_{DQ} = 2 \times 250\text{ mA}$ , $P_{IN} = 2\text{ W}$ , $f = 123\text{ MHz}$	450	580	-	W
$h_D$	$V_{DD} = 100\text{ V}$ , $I_{DQ} = 2 \times 250\text{ mA}$ , $P_{IN} = 2\text{ W}$ , $f = 123\text{ MHz}$		70	-	%

Table 6. Pulse / 1 msec - 10%

Symbol	Test conditions	Min.	Typ.	Max.	Unit
$P_{OUT}$	$V_{DD} = 100\text{ V}$ , $I_{DQ} = 2 \times 250\text{ mA}$ , $P_{IN} = 8\text{ W}$ , $f = 123\text{ MHz}$	-	900	-	W
$h_D$	$V_{DD} = 100\text{ V}$ , $I_{DQ} = 2 \times 250\text{ mA}$ , $P_{IN} = 8\text{ W}$ , $f = 123\text{ MHz}$	-	65	-	%

### 3 Impedances

Figure 2. Impedance data

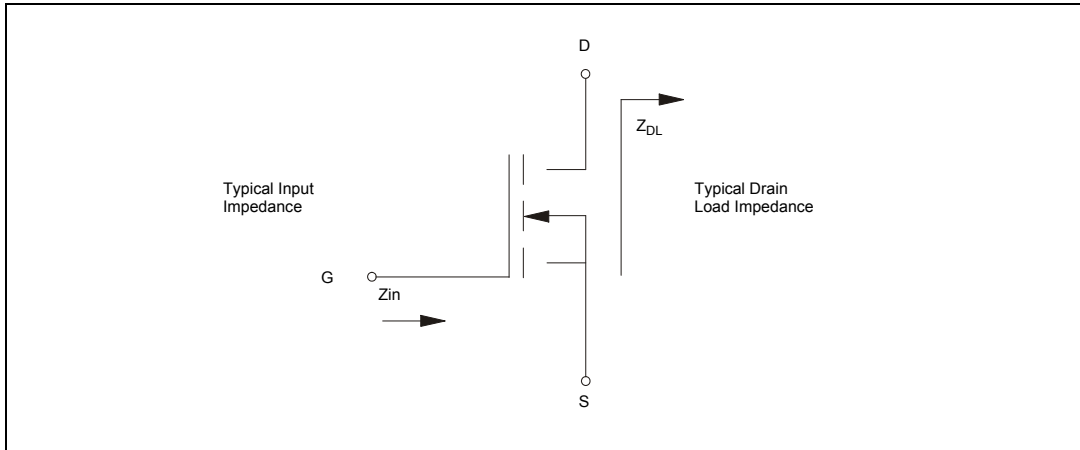


Table 7. Impedance data

Freq.	$Z_{IN}$ ( $\Omega$ )	$Z_{DL}$ ( $\Omega$ )
123 MHz (pulse)	$1.0 - j 4.80$	$6.3 + j 10.5$
123 MHz (CW)	$0.8 - j 3.45$	$5.0 + j 13.0$
64 MHz	$1.4 - j 10.0$	$12.8 + j 14.0$

Note: Measured gate-to-gate and drain-to-drain, respectively.

# 4 Electrical schematic and BOM

Figure 3. Electrical schematic

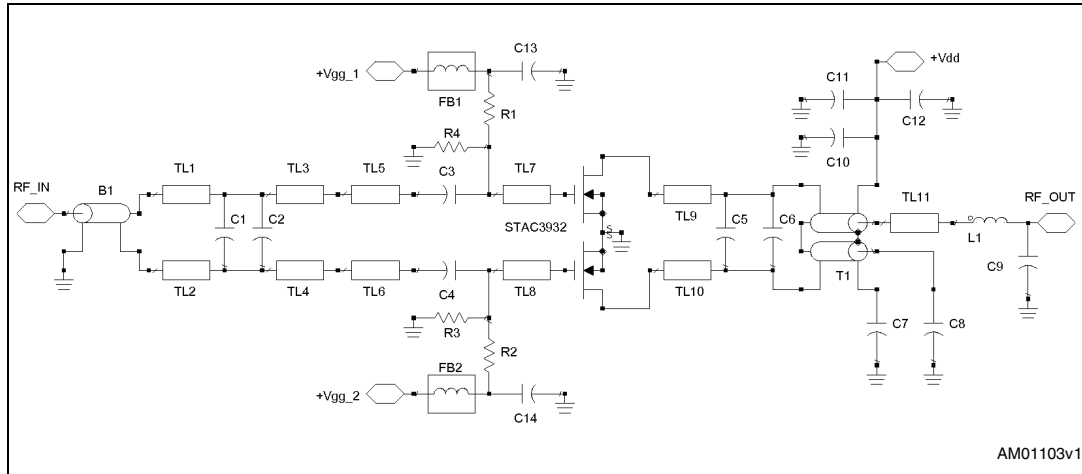


Table 8. Bill of materials

Component	Description
C1	270 pF ATC 100B chip capacitor
C2	180 pF ATC 100B chip capacitor
C3, C4	750 pF ATC 700B chip capacitor
C5, C8	43 pF ATC 100B chip capacitor
C6	20 pF ATC 100B chip capacitor
C7	1000 pF ATC 100C chip capacitor
C9	5.6 pF ATC 100B chip capacitor
C10	2200 pF ATC 100C chip capacitor
C11	470 pF ATC 100B chip capacitor
C12	100 $\mu$ F, 200 V electrolytic capacitor
C13, C14	1200 pF ATC 700B chip capacitor
R1, R2	15 $\Omega$ 1/4 watt chip resistor
R3, R4	30 $\Omega$ 1/4 watt axial lead resistor
L1	3 turns, 16 ga magnet wire, Id 3/8", .165" turn spacing, 78 nH
FB1, FB2	Ferrite bead, Fair-Rite # 2743019447
B1	1/4 $\lambda$ balun transformer, RG316-25 $\Omega$ , 16.5"
T1	20 ga Teflon-coated wire through 4 copper tubes OD 1/8" x 1.5"
TL1, TL2	0.740" x 0.200" microstrip
TL3, TL4	0.360" x 0.200" microstrip

Table 8. Bill of materials (continued)

Component	Description
TL5, TL6	0.480" x 0.350" microstrip
TL7, TL8	0.220" x 0.350" microstrip
TL9, TL10	0.350" x 0.660" microstrip
TL11	0.415" x 0.200" microstrip
Board	0.062" FR-4

# 5 Circuit layout

Figure 4. Circuit photo

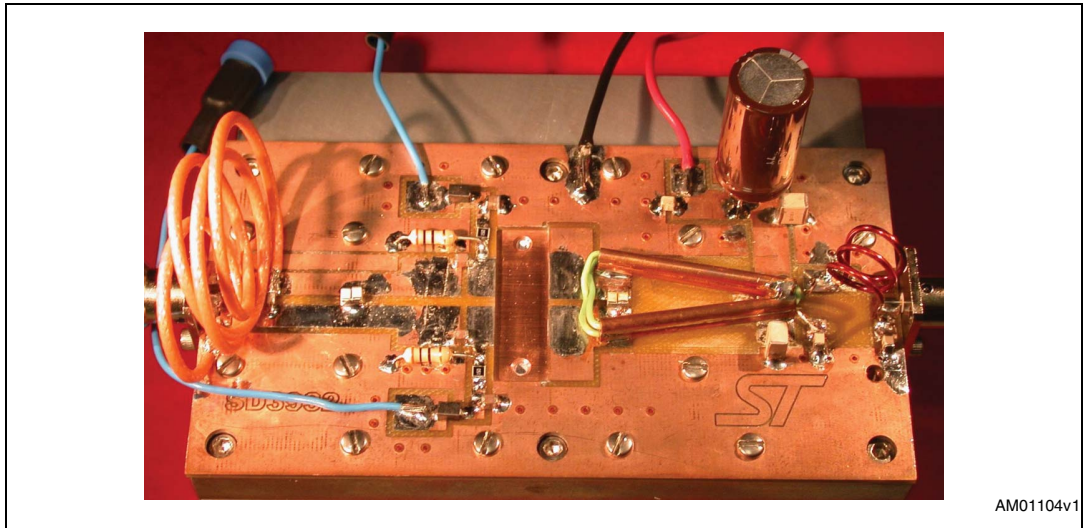
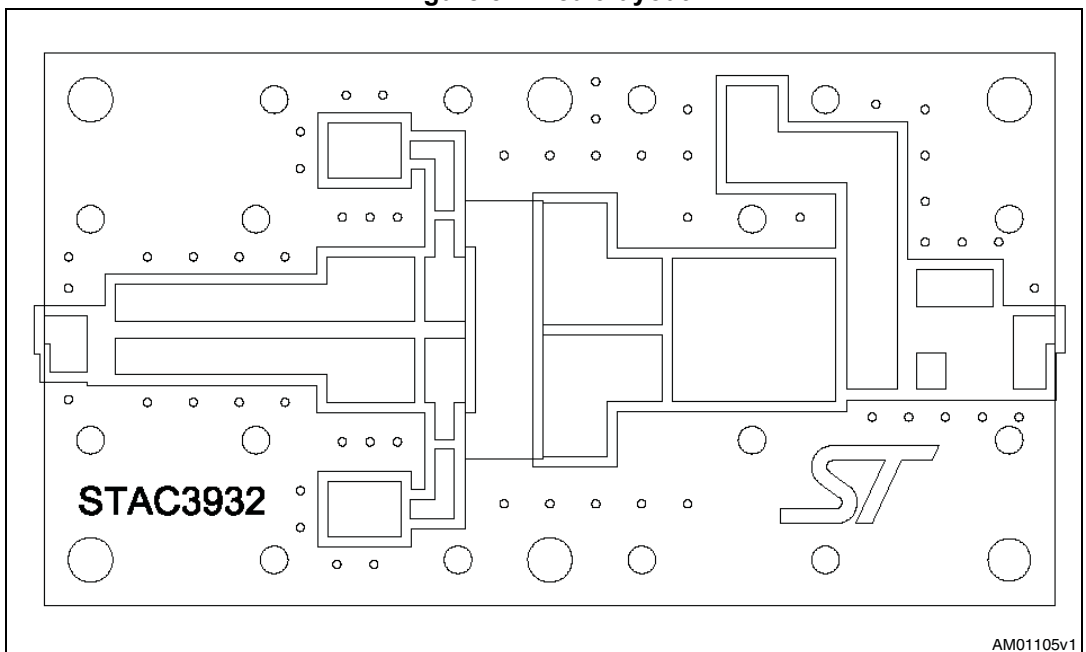


Figure 5. Circuit layout





## 6 Typical performance

Figure 6. Capacitances vs. drain supply voltage

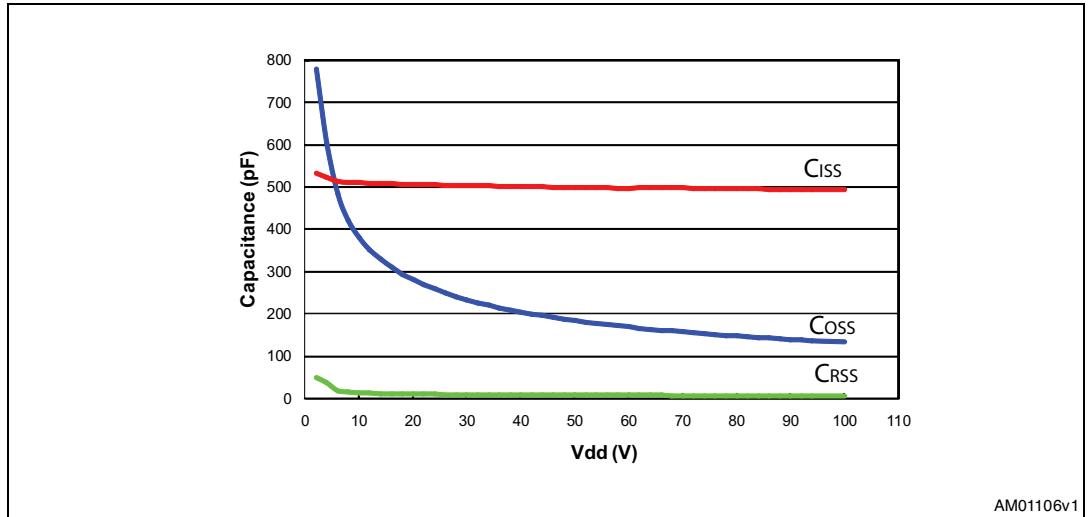


Figure 7. Maximum safe operating area

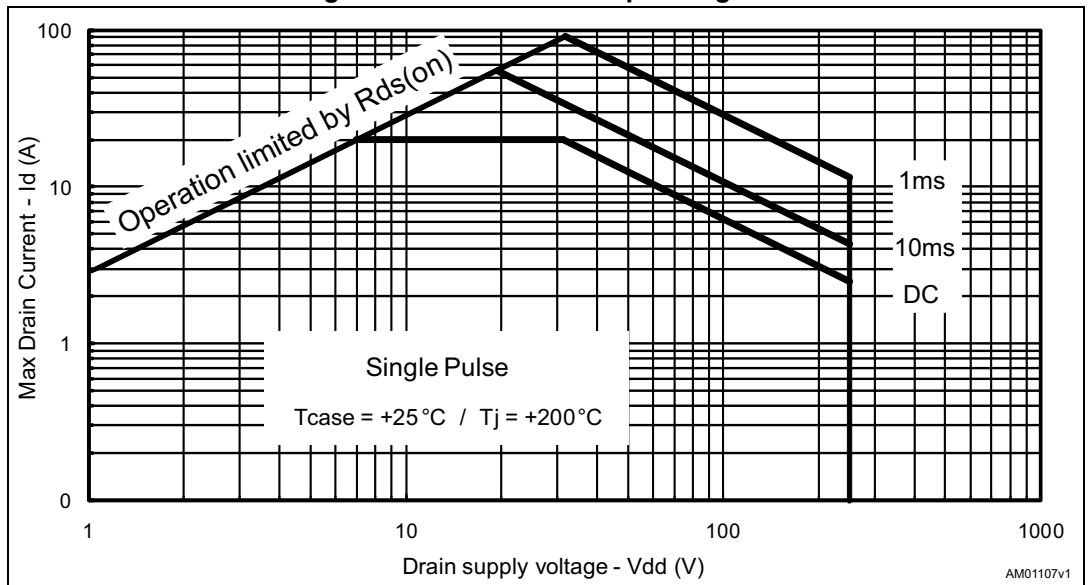


Figure 8. Transient thermal impedance

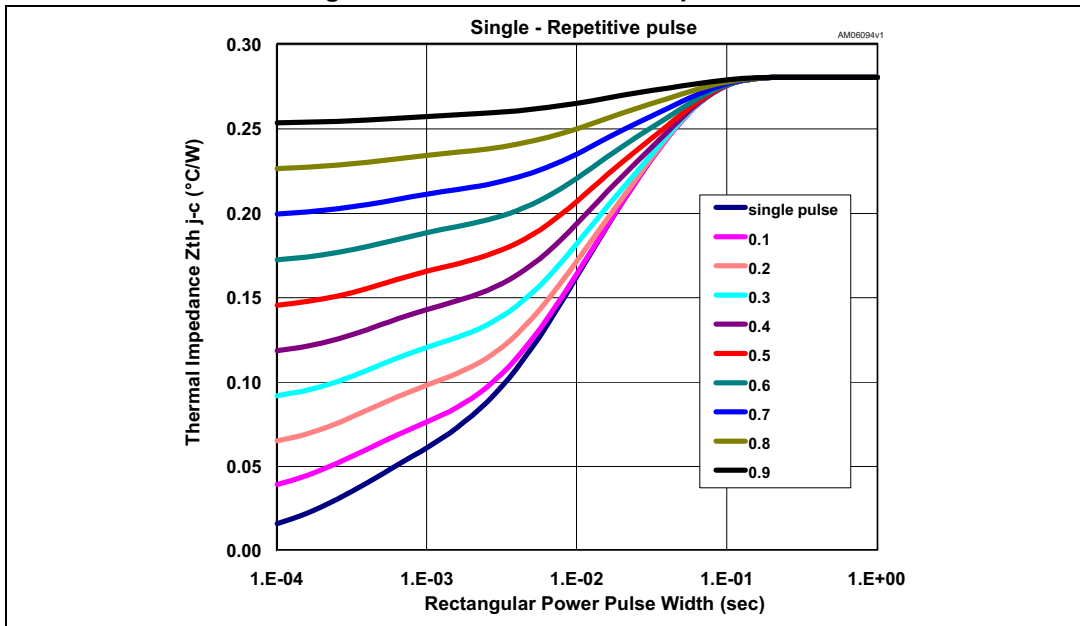


Figure 9. Transient thermal model

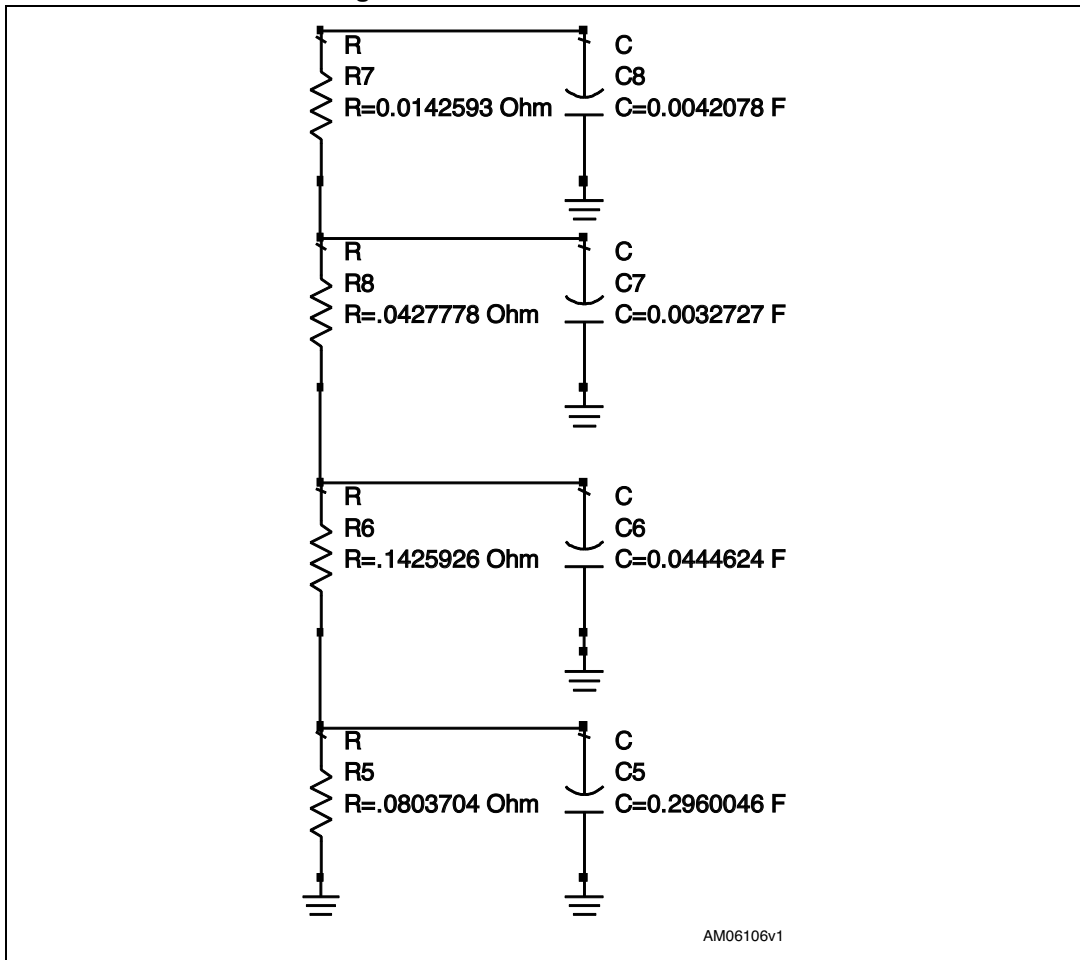
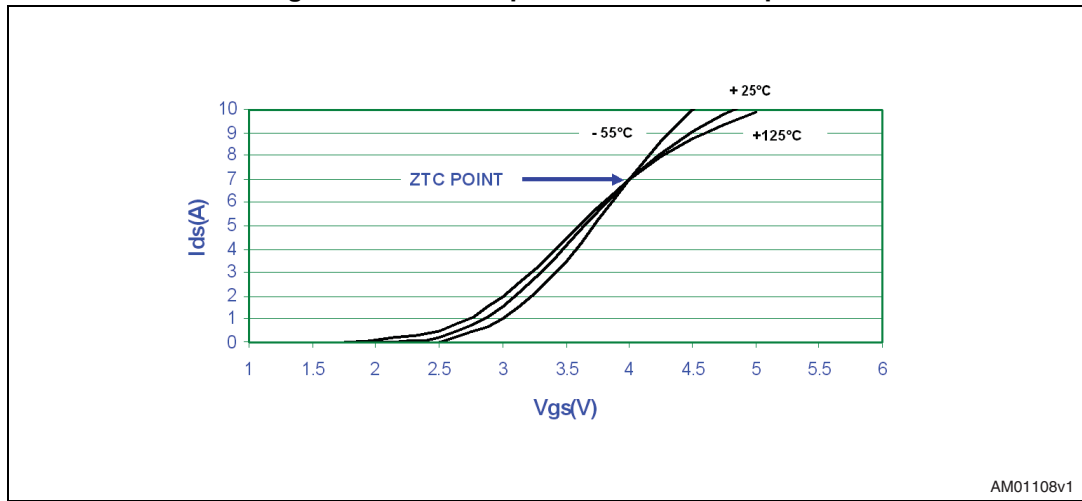
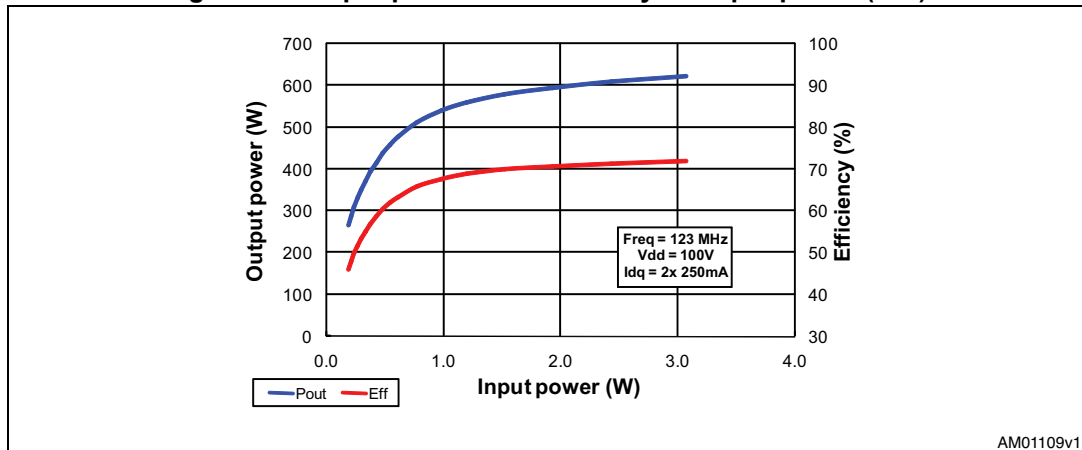


Figure 10. Zero temperature coefficient point



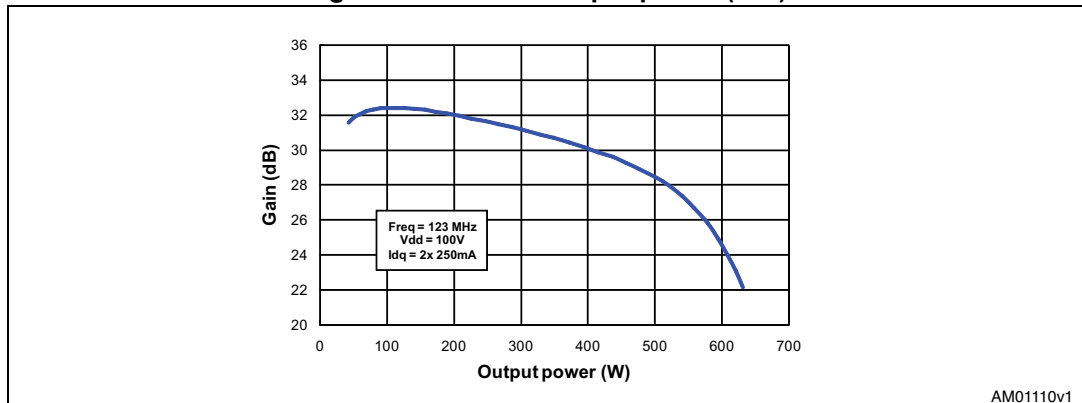
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Figure 11. Output power and efficiency vs. input power (CW)



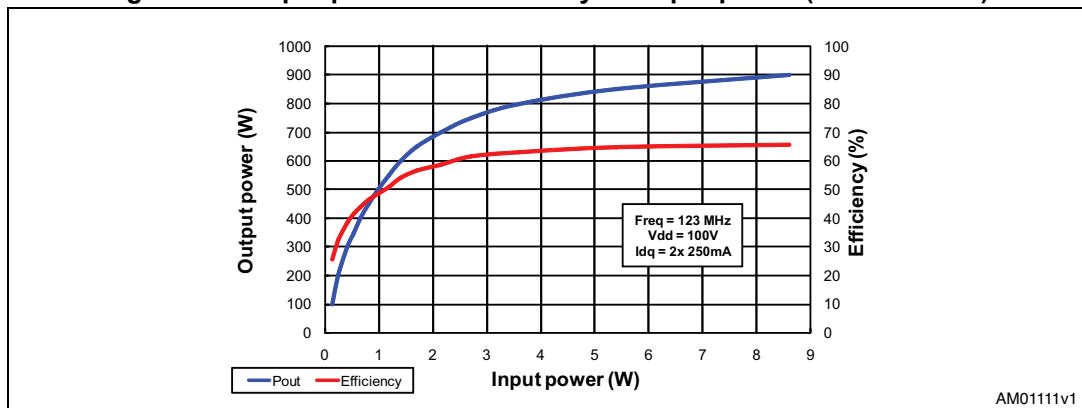
AM01109v1

Figure 12. Gain vs. output power (CW)



AM01110v1

Figure 13. Output power and efficiency vs. input power (1 msec - 10%)



AM01111v1

## 7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

**Table 9. STAC244B mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	5.08		5.59
A1	4.32		4.83
B	4.32		5.33
C	9.65		9.91
D	17.78		18.08
E	33.88		34.19
F	0.10		0.15
G		1.02	
H	1.45		1.70
I	4.83		5.33
J	9.27		9.52
K	27.69		28.19
L		3.23	
M		3.45	

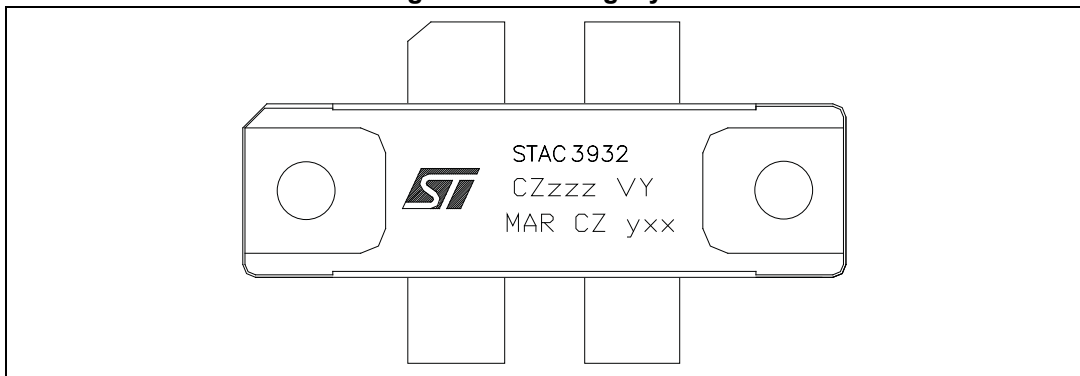


## 8 Marking, packing and shipping specifications

**Table 10. Packing and shipping specifications**

Order code	Packaging	Pcs per tray	Dry pack humidity	Lot code
STAC3932B	Tray	20	< 10%	Not mixed

**Figure 15. Marking layout**



**Table 11. Marking specifications**

Symbol	Description
CZ	Assembly plant
zzz	Last 3 digits of diffusion lot
VY	Diffusion plant
MAR	Country of origin
CZ	Test and finishing plant
y	Assembly year
xx	Assembly week

## 9 Revision history

**Table 12. Document revision history**

Date	Revision	Changes
06-Mar-2009	1	First release.
18-Feb-2010	2	Updated description on cover page
16-Mar-2010	3	Updated <i>Figure 7: Maximum safe operating area</i> . Added <i>Figure 8: Transient thermal impedance</i> . and <i>Figure 9: Transient thermal model</i> .
06-Jul-2011	4	Updated <i>Chapter 7: Package mechanical data</i> . Added <i>Chapter 8: Marking, packing and shipping specifications</i> .
22-Sep-2011	5	Update values for L and M in <i>Table 9: STAC244B mechanical data</i> .
01-Jul-2013	6	Modified pin labeling in <i>Figure 1: Pin connection</i> . Minor text corrections throughout document.



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